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## JAN2N6437 (#23951)

### Products

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#### Overview

#### Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
DC Current Gain	HFE	30.00		120.00	
Turn Off Time (nS)	$t_{off}$			1250.00	ns

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector Current (dc)	$I_C$			25.00	A
Collector-Emitter Voltage (Base Open)	$V_{CEO}$			100.00	V
Junction Temperature (°C)	$T_J$			200.00	°C

This part can be found in the following product categories:

- ▶ [Non-Radiation Hardened Devices](#) ▶ [Transistors](#) ▶ [BJT\( BiPolar Junction Transistor\)](#) ▶ [PNP Transistor](#)
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